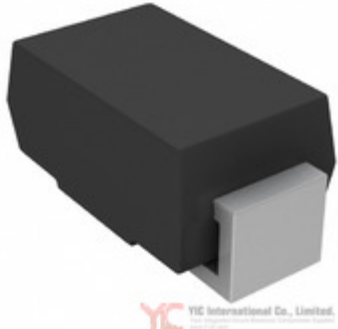
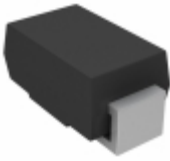
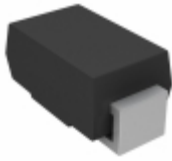


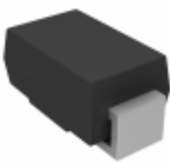
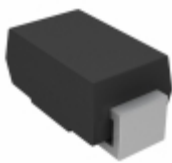


	<h2>S1DHE3/61T</h2>
	<p>Hersteller-Teilenummer: S1DHE3/61T</p> <p>Hersteller / Marke: Vishay / Semiconductor - Diodes Division</p> <p>Teil der Beschreibung: DIODE GEN PURP 200V 1A DO214AC</p> <p>Datenblätter: 1.S1DHE3/61T.pdf 2.S1DHE3/61T.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 17500 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	S1DHE3/61T
Hersteller	Vishay / Semiconductor - Diodes Division
Beschreibung	DIODE GEN PURP 200V 1A DO214AC
Kategorie	Diskrete Halbleiterprodukte > Dioden-Gleichrichter-
Teilstatus	17500 pcs Stock
Serie	-
Befestigungsart	Surface Mount
Verpackung / Gehäuse	DO-214AC, SMA
Supplier Device-Gehäuse	DO-214AC (SMA)
Diodentyp	Standard
Strom - Richt (Io)	1A
Spannung - Forward (Vf) (Max) @ If	1.1V @ 1A
Strom - Sperrleckstrom @ Vr	1µA @ 200V
Spannung - Sperr (Vr) (max)	200V
Geschwindigkeit	Standard Recovery >500ns, > 200mA (Io)
Rückwärts-Erholzeit (Trr)	1.8µs
Betriebstemperatur - Anschluss	-55°C ~ 150°C
Kapazität @ Vr, F	12pF @ 4V, 1MHz
Verpackung	Tape & Reel (TR)

S1DHE3/61T ist neu im Original, Suche S1DHE3/61T Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie S1DHE3/61T Vishay / Semiconductor - Diodes Division mit Garantie und Vertrauen. Anfrage S1DHE3/61T: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>S1DHE3_A/H Vishay / Semiconductor - Diodes Division DIODE GEN PURP 200V 1A DO214AC</p>	 <p>S1DHE3_A/H Electro-Films (EFI) / Vishay DIODE GEN PURP 200V 1A DO214AC</p>	 <p>S1DFS2MWG TSC (Taiwan Semiconductor) DIODE, 1A, 200V, AEC-Q101, SOD-1</p>	 <p>S1DHE3/61T Vishay / Semiconductor - Diodes Division DIODE GEN PURP 200V 1A DO214AC</p>
 <p>S1DHE3/5AT Electro-Films (EFI) / Vishay DIODE GEN PURP 200V 1A DO214AC</p>	 <p>S1DHE3_A/I Electro-Films (EFI) / Vishay DIODE GEN PURP 200V 1A DO214AC</p>	 <p>S1DFS2MXG TSC (Taiwan Semiconductor) DIODE, 1A, 200V, AEC-Q101, SOD-1</p>	 <p>S1DHE3/5AT Vishay / Semiconductor - Diodes Division DIODE GEN PURP 200V 1A DO214AC</p>

heiße Teile

Mehr

⚙ S1D13776B	↔ S1D13776B00B11B	↔ S1D13778B00B10B	D S1D13806F00A100	↔ S1D13A03B00B30B
↔ S1D13A04B00B20B	⚙ S1D13A05B00B200	D S1D15100F00C100	↔ S1D15201D00A000	↔ S1D15206F00A2
⚙ S1D15206F11A200	↔ S1D15208F00A200	⚙ S1D15607D00B000	↔ S1D15607T00C00C	↔ S1D15710D11B000
D S1D15714T00A00A	⚙ S1D15G27D00B000	↔ S1D16006D00A000	⚙ S1D16700D01A000	↔ S1D16702D00A000
↔ S1D16702F00A100	↔ S1D17202F00A100	⚙ S1D17901T00200A	↔ S1D17901T00500A	↔ S1D17901T00600A
↔ S1D17909T00400A	↔ S1D17909T01100A	D S1D17919T00600A	⚙ S1D17925T00400A	↔ S1D17925T00500A
⚙ S1D17925T01200A	D S1D19105D01B000	↔ S1D19122D00B000	↔ S1D2140B03-D0B0	↔ S1D2140B03-DO
↔ S1D2147A01-A0B0	⚙ S1D2500A01-DO	↔ S1D2504A01-D0B0	↔ S1D2506A01-D0B0	↔ S1D2507B01-AOBO
⚙ S1D2520X01-S0T0	↔ S1D2521X01-S0T0	⚙ S1D30300F01A200	D S1D30302F00A000	↔ S1D5514C09-AOBO
↔ S1D6S3N2D00Y000	⚙ S1DA-E3/5AT	↔ S1DA-E3/5AT	⚙ S1DB-13-F	↔ S1DHE3/61T

Contact us: Info@Y-IC.com

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